CHINA
SEMICONDUCTOR
CORPORATION

Spec. No.	PS-ND-08070510
Rev.	A

PRODUCT SPECIFICATION

Model No：CSD-424/425M9

Descriptions:

- 0.4 Inch Dual Digits Display
- CSD-424: Common Anode
- CSD-425: Common Cathode
- Emitting Color：Super Bright Green

CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

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Model No：CSD-424/425M9

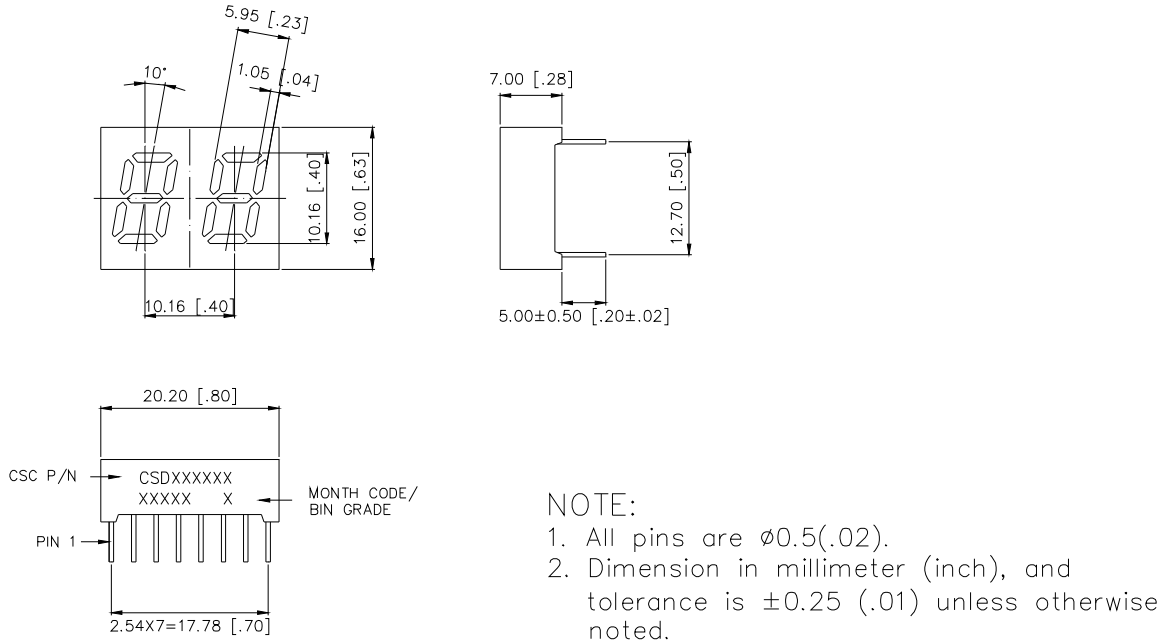
■ Features -

1. 0.4 inch (10.1mm) dight height.
2. Case mold type.
3. RoHs compliant.
4. Low power consumption.
5. Easy mounting on P.C. board or socket.

■ Device Selection Guide -

Part No.	Chip		Description
	Material	Emitted Color	
CSD-424M9	AlGaInP	Super Bright Green	Common Anode
CSD-425M9	AlGaInP	Super Bright Green	Common Cathode

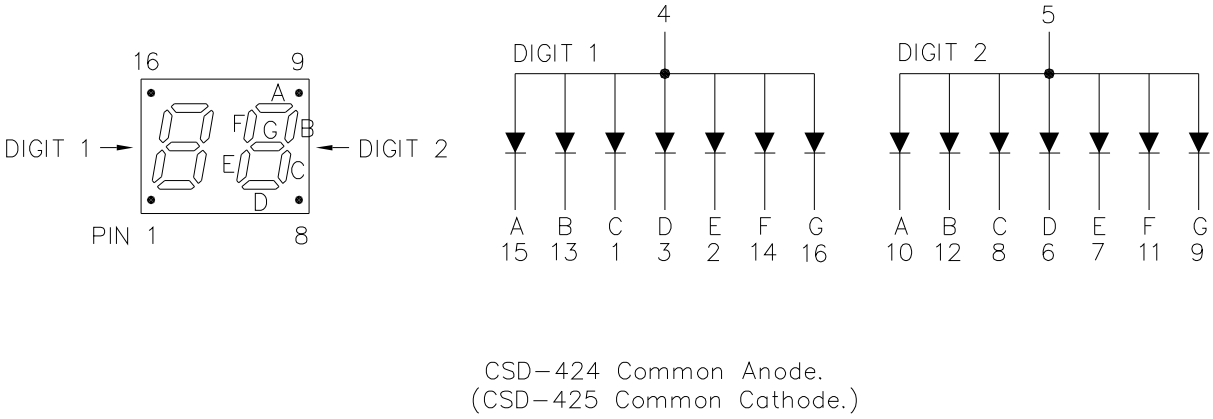
■ Package Dimensions -



NOTE:
1. All pins are ø0.5(.02).
2. Dimension in millimeter (inch), and tolerance is ±0.25 (.01) unless otherwise noted.

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■ Internal Circuit Diagrams -



CSD－424 Common Anode.
(CSD－425 Common Cathode.)

■ Absolute Maximum Rating -

(Ta=25℃)

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	Pd	70	mW
Continuous Forward Current Per Dice	I_{AF}	25	mA
Peak Current Per Dice(Duty cycle 1/10,1KHz)	I_{PF}	90	mA
Derating Linear From 25℃ Per Dice	-	0.33	mA/℃
Reverse Voltage Per Dice	V_R	5	V
Operating Temp.	Topr	-35 ~ +85	℃
Storage Temp.	Tstg	-35 ~ +85	℃
Solder temperature 1/16 inch below seating plane for 3 seconds at 260℃			

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■ Electro-optical Characteristics -

(Ta=25℃)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Segment	V_F	-	2.1	2.8	V	I_F=20mA
Luminous Intensity Per Segment	Iv	-	4	-	mcd	I_F=10mA
Peak Emission Wavelength	λp	-	570	-	nm	I_F=20mA
Dominant Wavelength	λd	-	568	-	nm	I_F=20mA
Spectrum Radiation Bandwidth	$\Delta \lambda$	-	30	-	nm	I_F=20mA
Reverse Current	IR	-	-	100	μA	V_R=5V
Luminous Intensity Matching Ratio	IV-m	-	-	2:1	-	I_F=10mA

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■ Typical Electrical / Optical Charateristics Curves -

(Ta = 25℃ Unless Otherwise Noted)

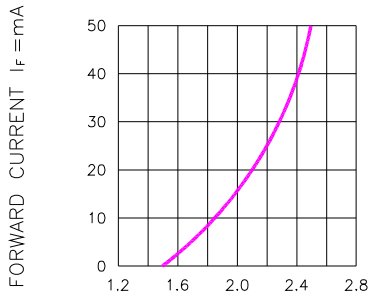


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

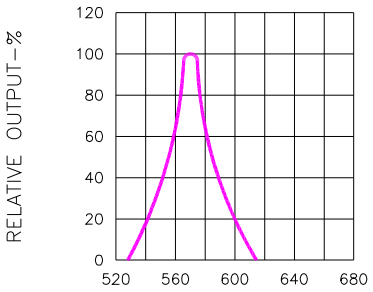


Fig.2 SPECTRAL RESPONSE

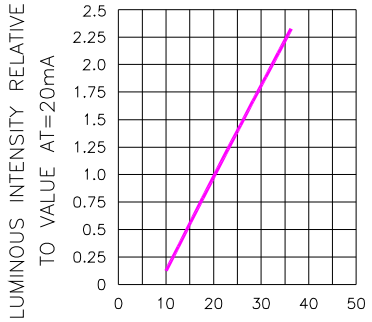


Fig.3 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

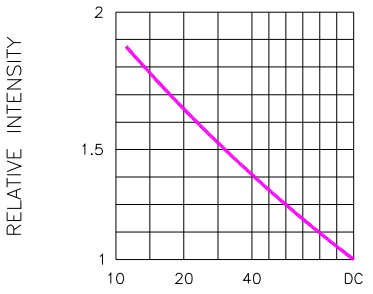


Fig.5 LUMINOUS INTENSITY VS. DUTY CYCLE

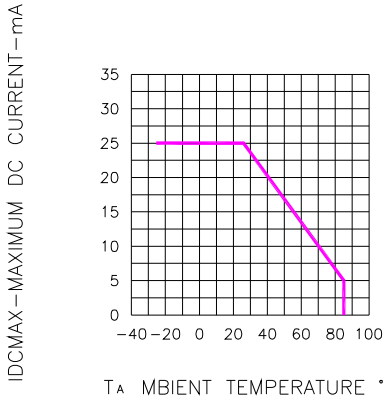


Fig.4 MAXIMUM ALLOWABLE DC CURRENT PER SEGMENT VS. A FUNCTION OF AMBIENT TEMPERATURE

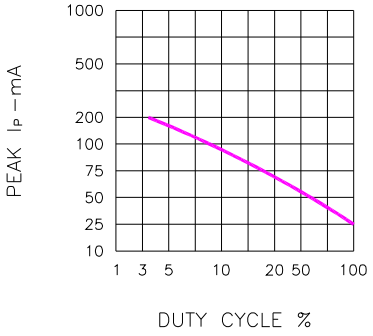


Fig.6 MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE f=1 KHz)